



Dual Switching Diode

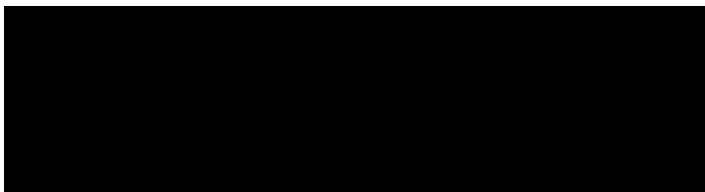


Features

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Application

Signal switching
High frequency rectifier



Ω **Maximum Ratings** ($T_a=25$ Unless otherwise specified)

Parameter	Symbol	Unit	Value
Device marking code			P
Repetitive peak reverse voltage	V_{RRM}	V	80
Forward current, per leg	I_F	mA	100
Non-repetitive Surge peak forward current @ $t=8.3\text{ms}$ half-sine wave	I_{FSM}	A	2
Non-repetitive Surge peak forward current @ $t=1\text{ms}$ square wave			2
Power dissipation	P_D	mW	200
Junction temperature	T_J	°C	-55 to +150
Storage temperature	T_{STG}	°C	-55 to +150



DAP202

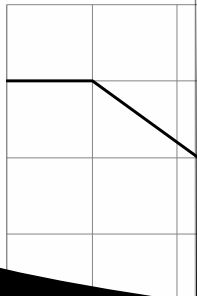
RoHS
COMPLIANT

Parameter	Symbol	Unit	
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ΩCharacteristics

Fig 1





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Preferred P/N	Packing
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